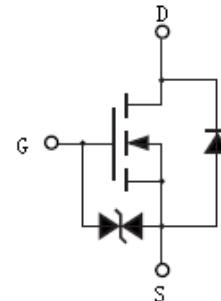




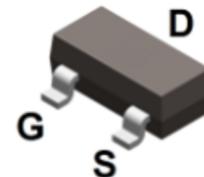
Features

- Low on-resistance
- High-speed switching
- Drive circuits can be simple
- Parallel use is easy
- HBM: JESD22-A114-B: 2



Typical Applications

- N-channel enhancement mode effect transistor
- Switching application



Mechanical Data

- Case: SOT-23
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin-Plated Leads, Solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
2N7002SH	SOT-23	3000 pcs / Tape & Reel	7002K.

Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V
Gate -Source Voltage	V_{GSS}	± 20	V
Continuous Drain Current ($T_A = 25^\circ\text{C}$) *1	I_D	300	mA
Continuous Drain Current ($T_A = 70^\circ\text{C}$) *1		240	mA
Pulsed Drain Current ($t_p = 10\mu\text{s}$, $T_A = 25^\circ\text{C}$)	I_{DM}	1200	mA
Power Dissipation ($T_A = 25^\circ\text{C}$) *1	P_D	0.35	W
Operating Junction Temperature Range	T_J	-55 ~ +150	°C
Storage Temperature Range	T_{STG}	-55 ~ +150	°C

Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	-	195	210	°C/W
Thermal Resistance Junction-to-Air *1	$R_{\theta JA}$	-	300	357	°C/W



Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
V_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu\text{A}$	60	-	-	V
I_{BS}	Drain to Source Leakage Current	$V_{DS} = 60V, V_{GS} = 0V$	-	-	1	μA
I_{GS}	Gate-body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	± 10	μA
On Characteristics						
$R_{DS(ON)}$	Drain-Source On-resistance ^{*2}	$V_{GS} = 10V, I_D = 0.5\text{A}$	-	2	2.5	Ω
		$V_{GS} = 5V, I_D = 0.05\text{A}$	-	1.8	3	
		$V_{GS} = 4.5V, I_D = 0.5\text{A}$	-	2.4	4	
$V_{GS(TH)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1	1.5	2.5	V
Dynamic Characteristics						
C_{ISS}	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 20V$ $f = 1.0\text{MHz}$	-	16.5	-	pF
C_{OSS}	Output Capacitance		-	5.5	-	
C_{RSS}	Reverse Transfer Capacitance		-	1.5	-	
Switching Characteristics						
$t_{d(on)}$	Turn-on Delay Time ^{*3}	$V_{DD} = 30V, I_D = 0.2\text{A}$ $V_{GS} = 10V, R_G = 25\Omega$ $R_L = 150\Omega$	-	6	-	ns
t_r	Turn-on Rise Time ^{*3}		-	5	-	
$t_{d(off)}$	Turn-Off Delay Time ^{*3}		-	25	-	
t_f	Turn-Off Fall Time ^{*3}		-	15	-	
Q_G	Total Gate-Charge	$V_{DS} = 10V$ $V_{GS} = 4.5V$ $I_D = 0.2\text{A}$	-	0.37	-	nC
Q_{GS}	Gate to Source Charge		-	0.12	-	
Q_{GD}	Gate to Drain (Miller) Charge		-	0.16	-	
Source-Drain Diode Characteristics						
V_{SD}	Diode Forward Voltage ^{*2}	$I_S = 0.3\text{A}, V_{GS} = 0V$	-	0.85	1.2	V

Notes:

1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper
2. The data tested by pulsed, pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
3. Guaranteed by design, not subject to production



Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

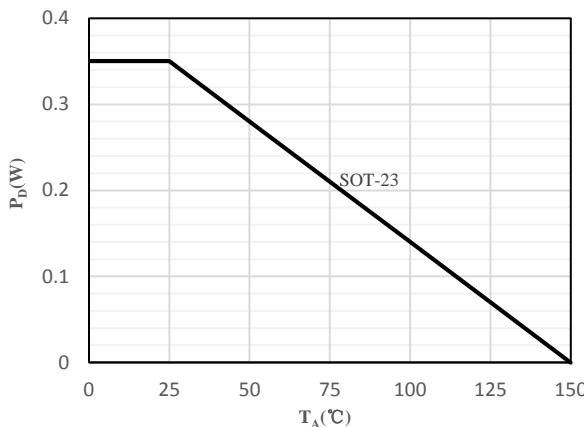


Fig 1 Power Dissipation

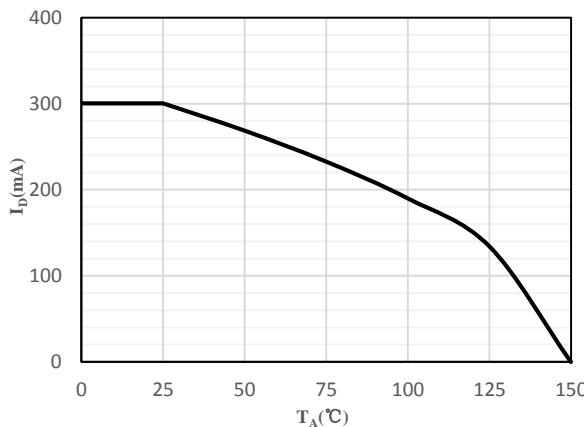


Fig 2 Drain Current

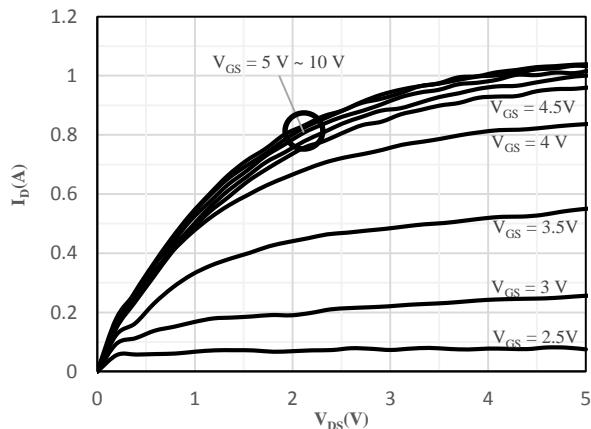


Fig 3 Typical Output Characteristics

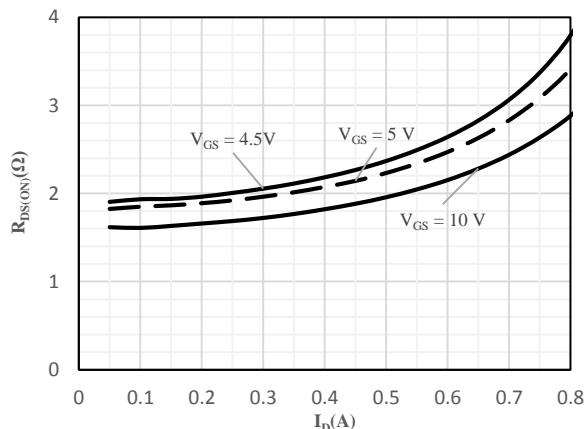


Fig 4 On-Resistance vs. Drain Current and Gate Voltage

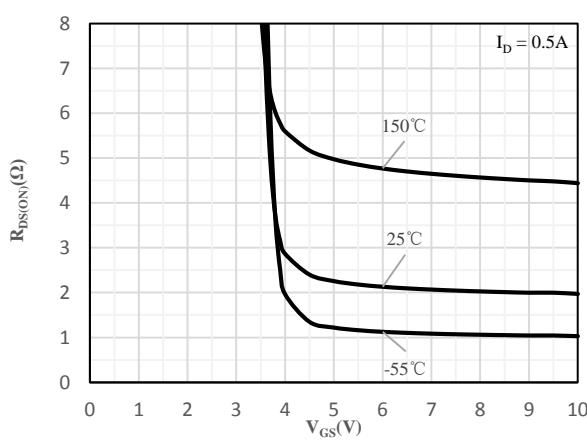


Fig 5 On-Resistance vs. Gate-Source Voltage

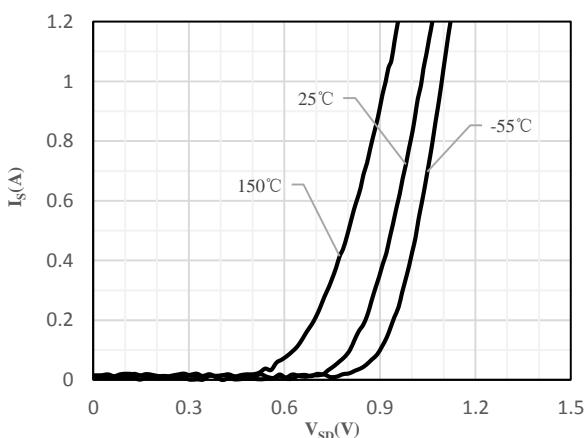


Fig 6 Body-Diode Characteristics

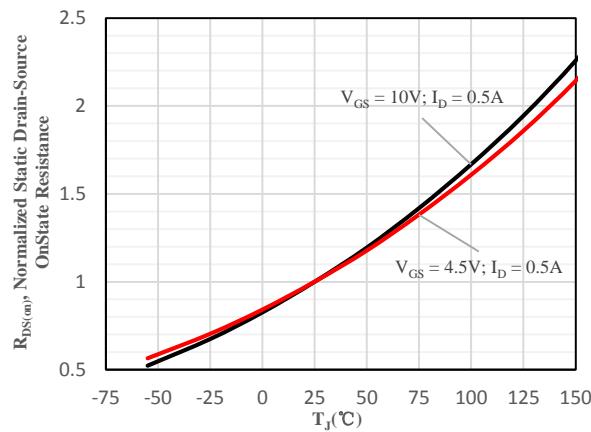


Fig 7 Normalized On-Resistance vs. Junction Temperature

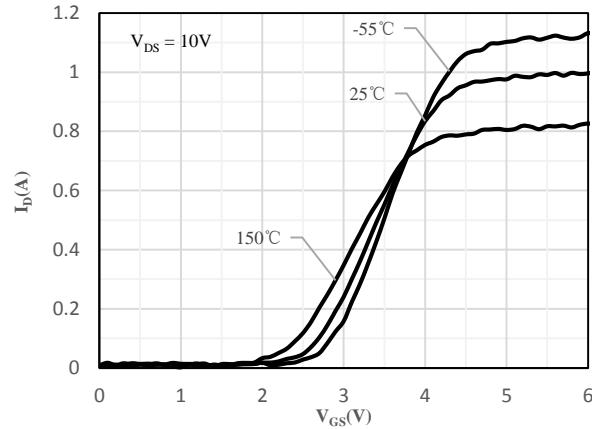


Fig 8 Transfer Characteristics

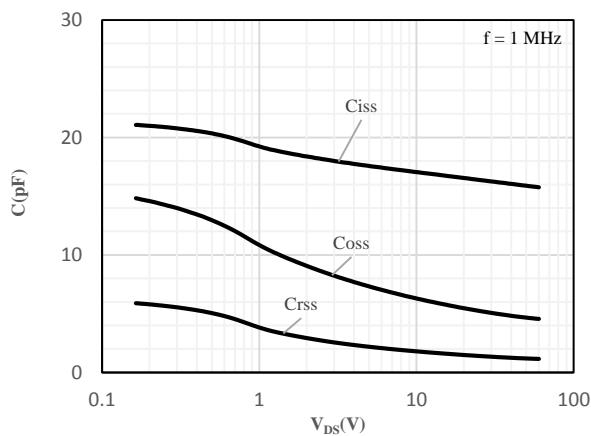


Fig 9 Capacitance Characteristics

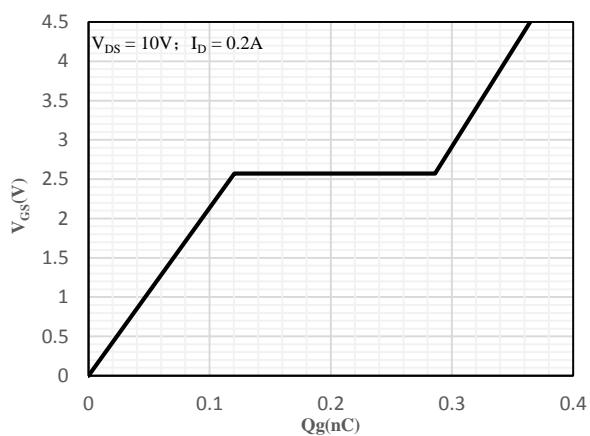


Fig 10 Gate-Charge Characteristics

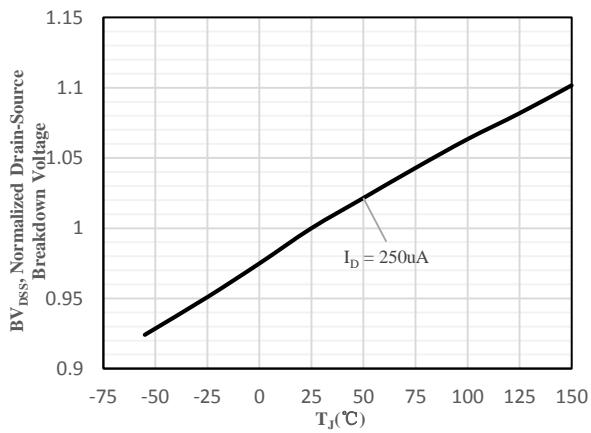


Fig 11 Normalized Breakdown Voltage vs. Junction Temperature

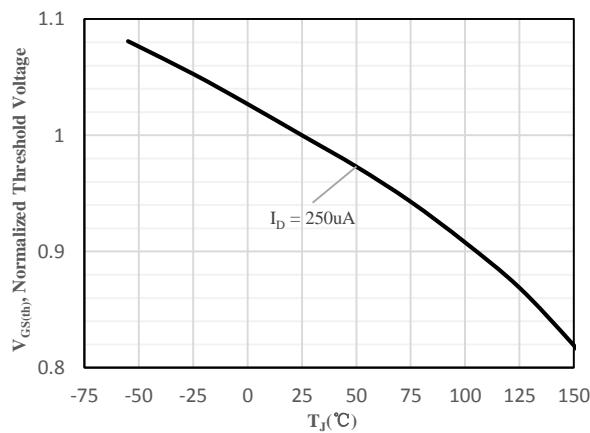


Fig 12 Normalized $V_{GS(th)}$ vs. Junction Temperature

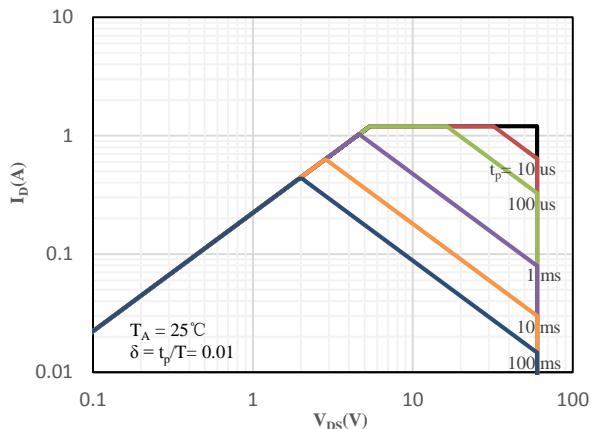


Fig 13 Safe Operating Area

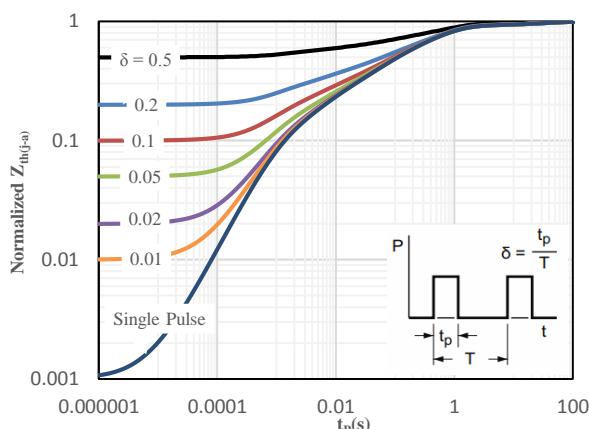
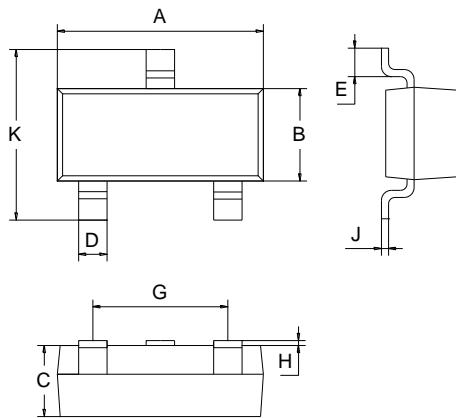


Fig 14 Normalized Maximum transient thermal impedance



Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.90	1.10
D	0.30	0.50
E	0.35	0.48
G	1.80	2.00
H	0.02	0.10
J	0.05	0.15
K	2.20	2.60

Mounting Pad Layout (Unit: mm)

SOT-23

